

# Darlington Complementary Silicon Power Transistors

... designed for general-purpose amplifier and low-frequency switching applications.

- High DC Current Gain @  $I_C = 10 \text{ Adc}$  —  
 $h_{FE} = 2400$  (Typ) — 2N6282, 2N6283, 2N6284  
 $= 4000$  (Typ) — 2N6285, 2N6286, 2N6287
- Collector-Emitter Sustaining Voltage —  
 $V_{CEO(sus)} = 60 \text{ Vdc}$  (Min) — 2N6282, 2N6285  
 $= 80 \text{ Vdc}$  (Min) — 2N6283, 2N6286  
 $= 100 \text{ Vdc}$  (Min) — 2N6284, 2N6287
- Monolithic Construction with Built-In Base-Emitter Shunt Resistors

## \*MAXIMUM RATINGS

Rating	Symbol	2N6282 2N6285	2N6283 2N6286	2N6284 2N6287	Unit
Collector-Emitter Voltage	$V_{CEO}$	60	80	100	Vdc
Collector-Base Voltage	$V_{CB}$	60	80	100	Vdc
Emitter-Base Voltage	$V_{EB}$	5.0			Vdc
Collector Current — Continuous Peak	$I_C$	20 40			A <sub>dc</sub>
Base Current	$I_B$	0.5			A <sub>dc</sub>
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	160 0.915			Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-65 to +200			$^\circ\text{C}$

## \*THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.09	$^\circ\text{C/W}$

\* Indicates JEDEC Registered Data.

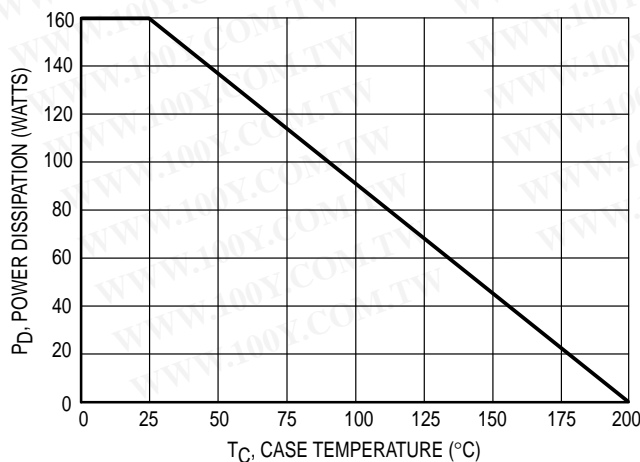


Figure 1. Power Derating

Preferred devices are Motorola recommended choices for future use and best overall value.

**NPN**  
**2N6282**

thru

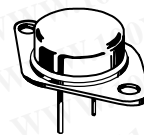
**2N6284\***  
**PNP**  
**2N6285**

thru

**2N6287\***

\*Motorola Preferred Device

**DARLINGTON**  
**20 AMPERE**  
**COMPLEMENTARY**  
**SILICON**  
**POWER TRANSISTORS**  
**60, 80, 100 VOLTS**  
**160 WATTS**



**CASE 1-07**  
**TO-204AA**  
**(TO-3)**

## 2N6282 thru 2N6284 2N6285 thru 2N6287

\*ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Collector-Emitter Sustaining Voltage ( $I_C = 0.1 \text{ A dc}$ , $I_B = 0$ )	$V_{CE(sus)}$	60 80 100	—	Vdc
Collector Cutoff Current ( $V_{CE} = 30 \text{ Vdc}$ , $I_B = 0$ ) ( $V_{CE} = 40 \text{ Vdc}$ , $I_B = 0$ ) ( $V_{CE} = 50 \text{ Vdc}$ , $I_B = 0$ )	$I_{CEO}$	— — —	1.0 1.0 1.0	mAdc
Collector Cutoff Current ( $V_{CE} = \text{Rated } V_{CB}$ , $V_{BE(off)} = 1.5 \text{ Vdc}$ ) ( $V_{CE} = \text{Rated } V_{CB}$ , $V_{BE(off)} = 1.5 \text{ Vdc}$ , $T_C = 150^\circ\text{C}$ )	$I_{CEX}$	— —	0.5 5.0	mAdc
Emitter Cutoff Current ( $V_{BE} = 5.0 \text{ Vdc}$ , $I_C = 0$ )	$I_{EBO}$	—	2.0	mAdc

### ON CHARACTERISTICS (1)

DC Current Gain ( $I_C = 10 \text{ A dc}$ , $V_{CE} = 3.0 \text{ Vdc}$ ) ( $I_C = 20 \text{ A dc}$ , $V_{CE} = 3.0 \text{ Vdc}$ )	$h_{FE}$	750 100	18,000 —	—
Collector-Emitter Saturation Voltage ( $I_C = 10 \text{ A dc}$ , $I_B = 40 \text{ mA dc}$ ) ( $I_C = 20 \text{ A dc}$ , $I_B = 200 \text{ mA dc}$ )	$V_{CE(sat)}$	— —	2.0 3.0	Vdc
Base-Emitter On Voltage ( $I_C = 10 \text{ A dc}$ , $V_{CE} = 3.0 \text{ Vdc}$ )	$V_{BE(on)}$	—	2.8	Vdc
Base-Emitter Saturation Voltage ( $I_C = 20 \text{ A dc}$ , $I_B = 200 \text{ mA dc}$ )	$V_{BE(sat)}$	—	4.0	Vdc

**勝特力材料 886-3-5753170**  
**勝特力电子(上海) 86-21-54151736**  
**勝特力电子(深圳) 86-755-83298787**  
[Http://www.100y.com.tw](http://www.100y.com.tw)

### DYNAMIC CHARACTERISTICS

Magnitude of Common Emitter Small-Signal Short-Circuit Forward Current Transfer Ratio ( $I_C = 10 \text{ A dc}$ , $V_{CE} = 3.0 \text{ Vdc}$ , $f = 1.0 \text{ MHz}$ )	$ h_{fe} $	4.0	—	MHz
Output Capacitance ( $V_{CB} = 10 \text{ Vdc}$ , $I_E = 0$ , $f = 0.1 \text{ MHz}$ )	$C_{ob}$	— —	400 600	pF
Small-Signal Current Gain ( $I_C = 10 \text{ A dc}$ , $V_{CE} = 3.0 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )	$h_{fe}$	300	—	—

\* Indicates JEDEC Registered Data.

(1) Pulse test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle = 2%

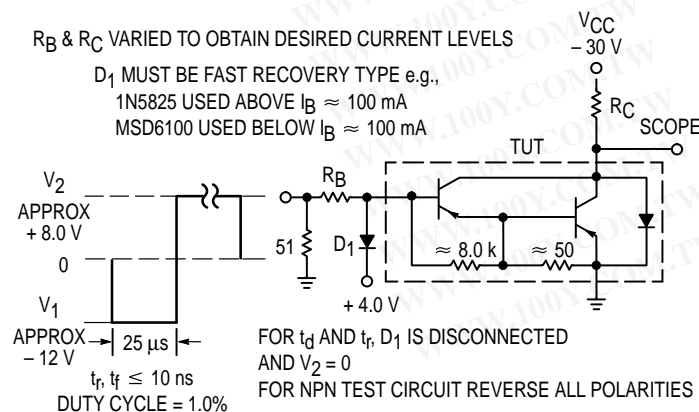


Figure 2. Switching Times Test Circuit

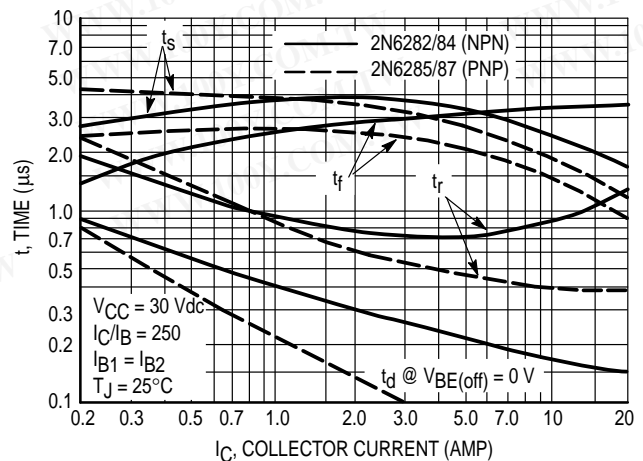


Figure 3. Switching Times

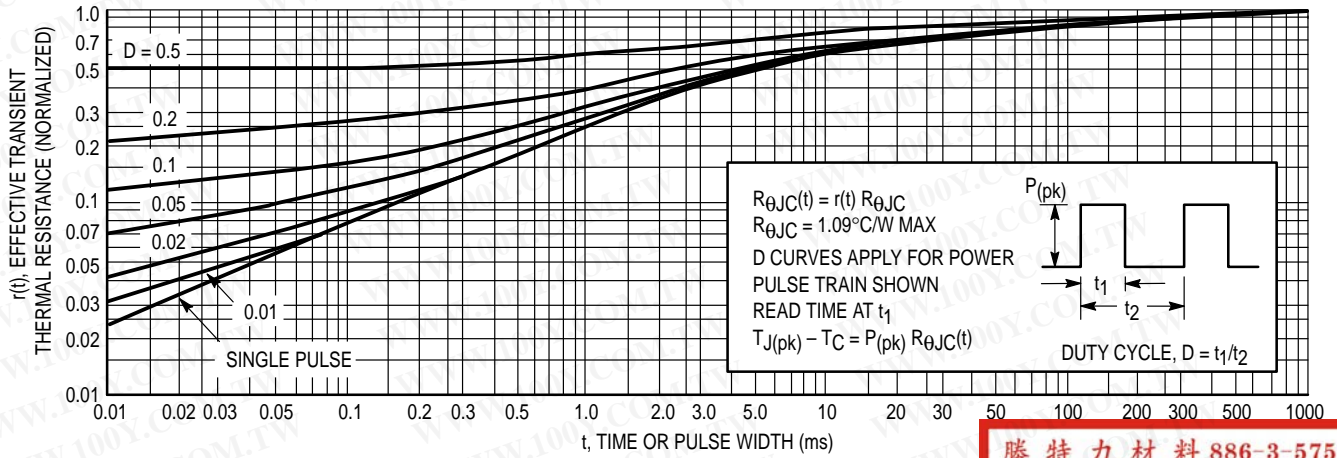


Figure 4. Thermal Response

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ACTIVE-REGION SAFE OPERATING AREA

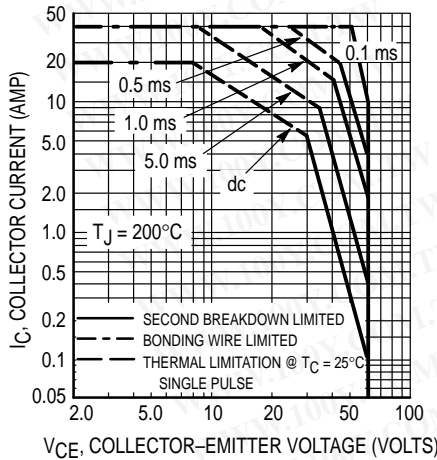


Figure 5. 2N6282, 2N6285

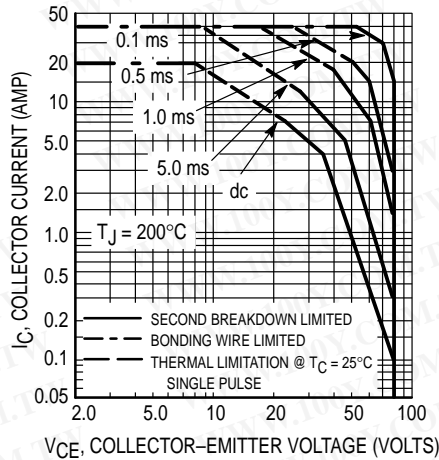


Figure 6. 2N6283, 2N6286

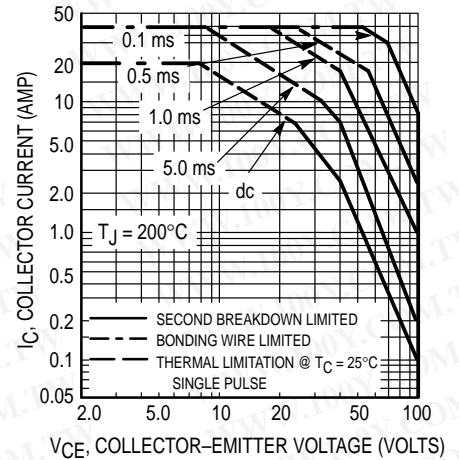


Figure 7. 2N6284, 2N6287

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e. the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figures 5, 6 and 7 is based on  $T_{J(pk)} = 200^\circ\text{C}$ ;  $T_C$  is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(pk)} < 200^\circ\text{C}$ .  $T_{J(pk)}$  may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

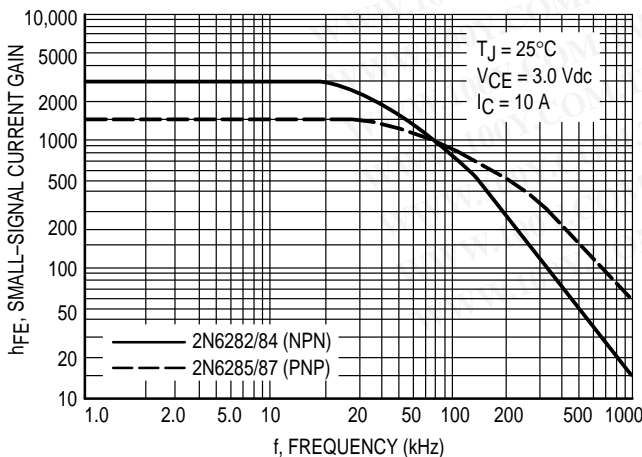


Figure 8. Small-Signal Current Gain

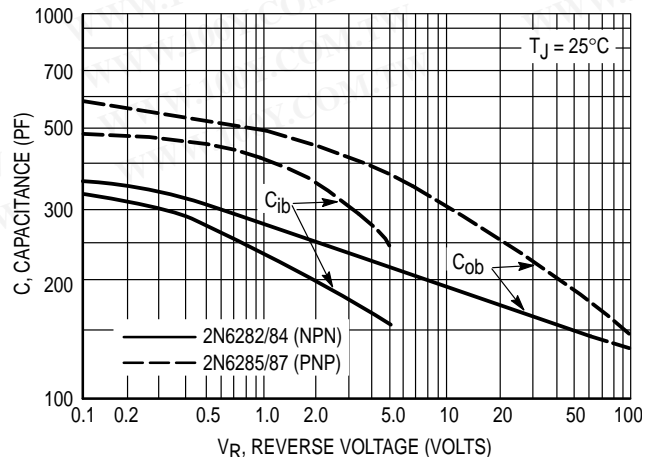
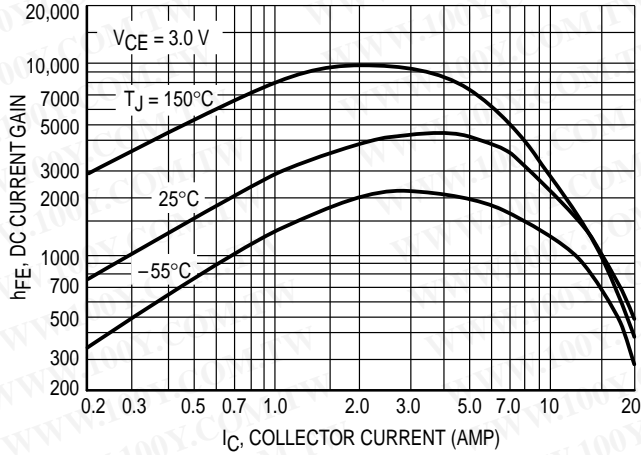


Figure 9. Capacitance

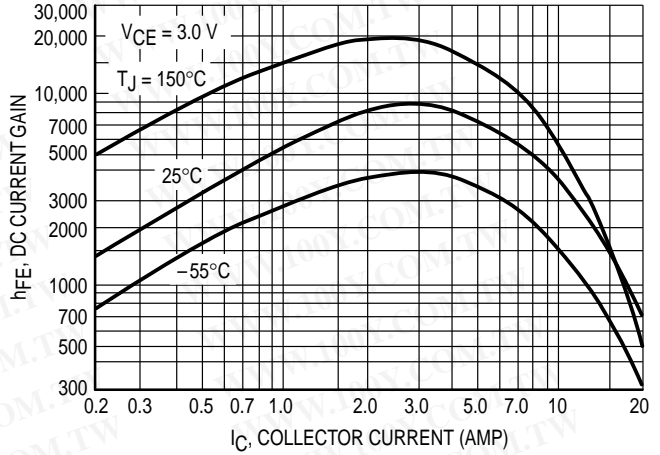


**2N6282 thru 2N6284 2N6285 thru 2N6287**

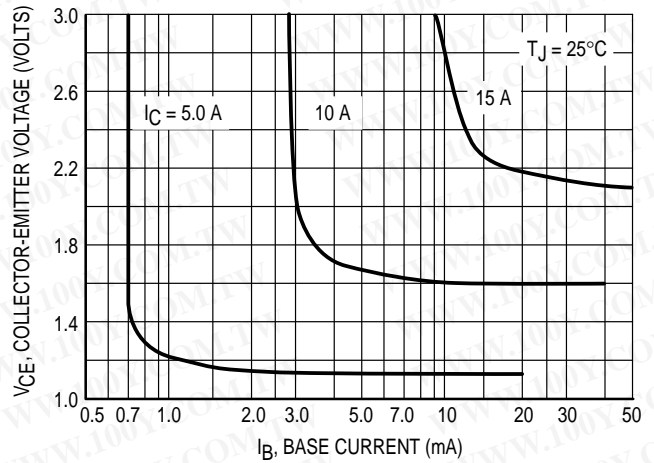
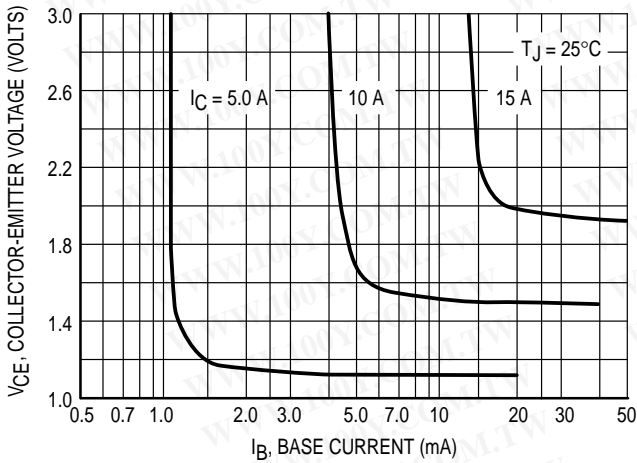
**NPN**  
2N6282, 2N6283, 2N6284



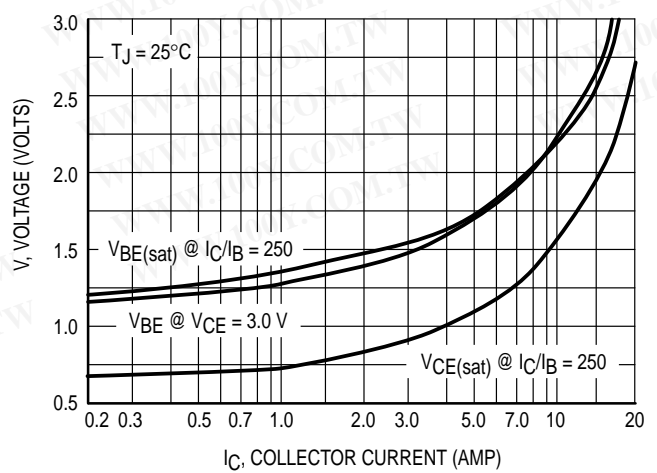
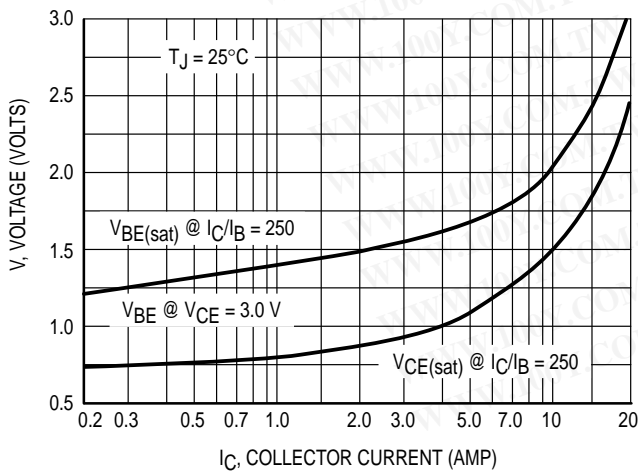
**PNP**  
2N6285, 2N6286, 2N6287



**Figure 10. DC Current Gain**



**Figure 11. Collector Saturation Region**



**Figure 12. "On" Voltages**

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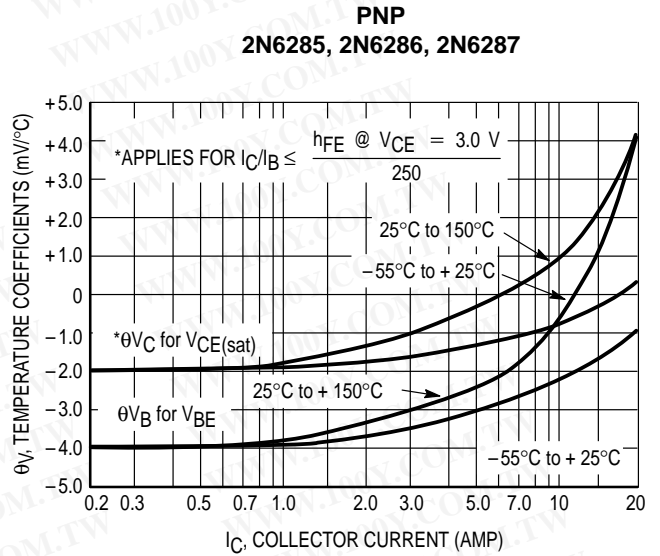
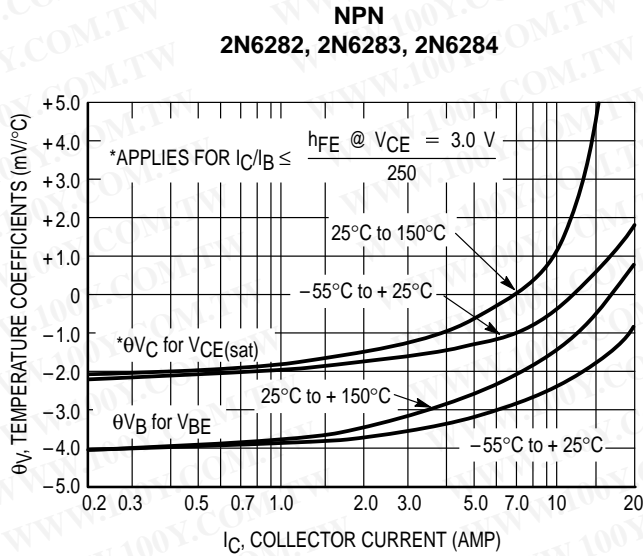


Figure 13. Temperature Coefficients

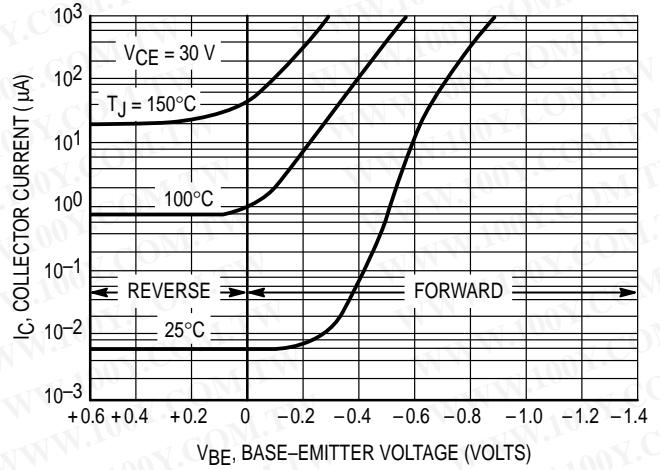
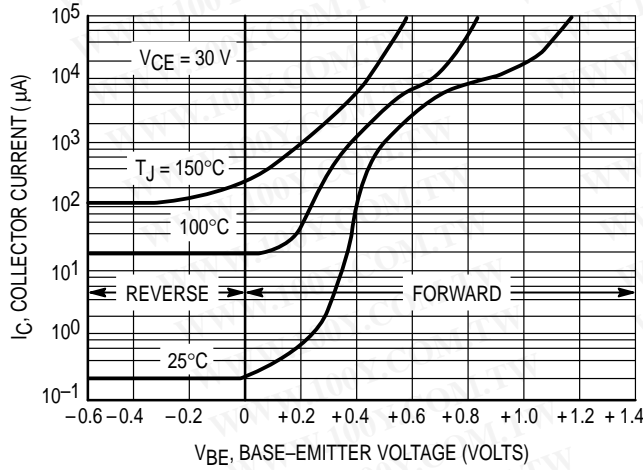


Figure 14. Collector Cut-Off Region

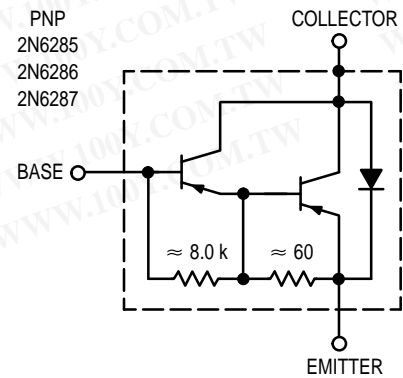
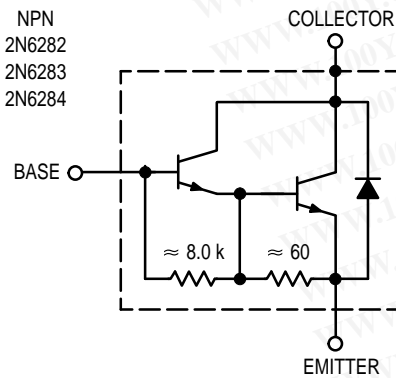
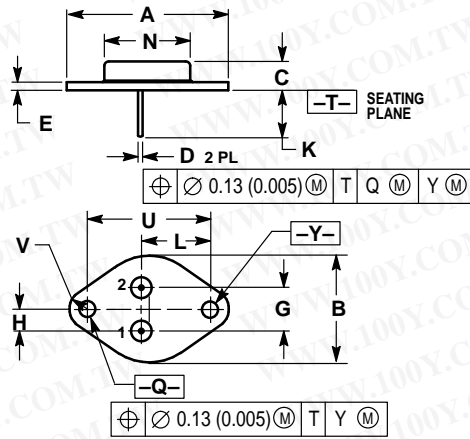


Figure 15. Darlington Schematic

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2N6282 thru 2N6284 2N6285 thru 2N6287

PACKAGE DIMENSIONS



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.550 REF		39.37 REF	
B	—	1.050	—	26.67
C	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
E	0.055	0.070	1.40	1.77
G	0.430 BSC		10.92 BSC	
H	0.215 BSC		5.46 BSC	
K	0.440	0.480	11.18	12.19
L	0.665 BSC		16.89 BSC	
N	—	0.830	—	21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC		30.15 BSC	
V	0.131	0.188	3.33	4.77

STYLE 1:  
 PIN 1. BASE  
 2. EMITTER  
 CASE: COLLECTOR

CASE 1-07  
 TO-204AA (TO-3)  
 ISSUE Z

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2N6282/D

